

HD74LV1G125A

Bus Buffer Gate with 3-state Output

REJ03D0071-0700 Rev.7.00 Mar 21, 2008

Description

The HD74LV1G125A has a bus buffer gate with 3–state output in a 5 pin package. Output is disabled when the associated output enable (\overline{OE}) input is high. To ensure the high impedance state during power up or power down, \overline{OE} should be connected to V_{CC} through a pull-down resistor; the minimum value of the resistor is determined by the current sourcing capability of the driver. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74LV125A

Supply voltage range: 1.65 to 5.5 V

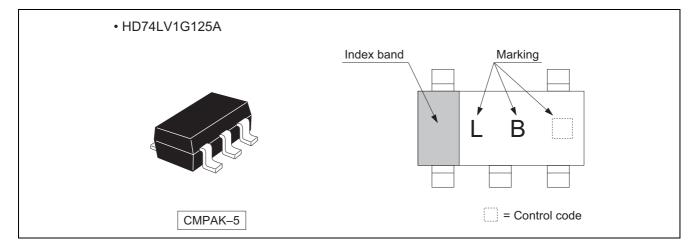
Operating temperature range : -40 to +85°C

- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V) All outputs V_{O} (Max.) = 5.5 V (@ V_{CC} = 0 V, Output : Z)
- Output current ± 6 mA (@V_{CC} = 3.0 V to 3.6 V), ± 12 mA (@V_{CC} = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

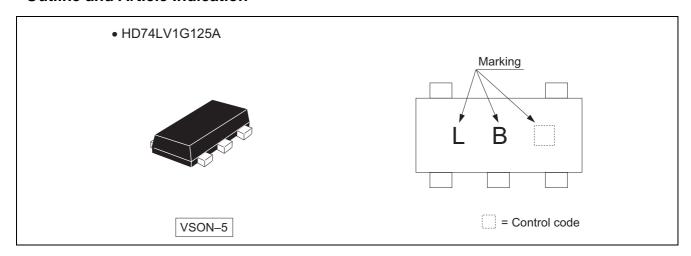
Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV1G125ACME	CMPAK-5 pin	PTSP0005ZC-A (CMPAK-5V)	СМ	E (3000 pcs/reel)
HD74LV1G125AVSE	VSON-5 pin	PUSN0005KA-A (TNP-5DV)	VS	E (3000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Outline and Article Indication



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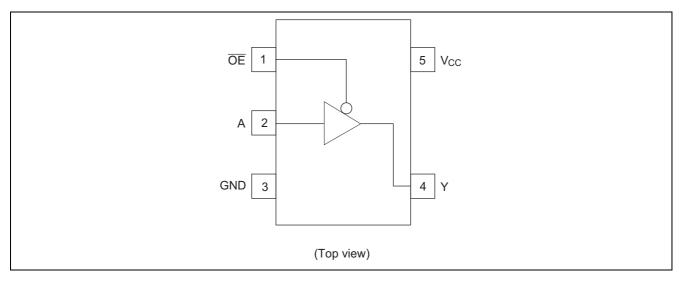


Function Table

Inp	Inputs					
ŌĒ	Α	Output Y				
L	Н	Н				
L	L	L				
Н	X	Z				

H : High level
L : Low level
X : Immaterial
Z : High impedance

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{cc}	-0.5 to 7.0	V	
Input voltage range *1	Vı	-0.5 to 7.0	V	
Output voltage range *1, 2	\/	-0.5 to V _{CC} + 0.5	V	Output : H or L
Cutput voltage range	Vo	-0.5 to 7.0] v	V _{CC} : OFF or Output : Z
Input clamp current	I _{IK}	-20	mA	V _I < 0
Output clamp current	I _{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I _O	±25	mA	$V_{\rm O} = 0$ to $V_{\rm CC}$
Continuous current through V _{CC} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes:

- The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V_{CC}	1.65	5.5	V	
Input voltage range	VI	0	5.5	V	
Output voltage range	Vo	0	V _{cc}	V	
Output voltage range	VO	0	5.5] v	Output : Z
		_	1		$V_{CC} = 1.65 \text{ to } 1.95 \text{ V}$
	I	_	2		$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
	l _{OL}	_	6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
Output ourrant		_	12	mA	V _{CC} = 4.5 to 5.5 V
Output current		_	-1		$V_{CC} = 1.65 \text{ to } 1.95 \text{ V}$
		_	-2		$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
	I _{OH}	_	-6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-12		V _{CC} = 4.5 to 5.5 V
		0	300		V _{CC} = 1.65 to 1.95 V
Input transition rise or fall rate	A+ / Ax	0	200	ns / V	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
Input transition rise or fall rate	Δt / Δv	0	100	115 / V	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		V _{CC} = 4.5 to 5.5 V
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristic

• $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{CC} (V) *	Min	Тур	Max	Unit	Test condition
		1.65 to 1.95	V _{CC} ×0.75	_	_		
	V _{IH}	2.3 to 2.7	V _{CC} ×0.7		_		
	VIH	3.0 to 3.6	V _{CC} ×0.7		_		
Input voltage		4.5 to 5.5	V _{CC} ×0.7	_	_	V	
input voltage		1.65 to 1.95	_	_	V _{CC} ×0.25	V	
	V_{IL}	2.3 to 2.7	_	_	V _{CC} ×0.3		
	VIL	3.0 to 3.6	_	_	V _{CC} ×0.3		
		4.5 to 5.5			V _{CC} ×0.3		
		1.8		0.25	_		
Hysteresis voltage	V _H	2.5		0.30	_	V	$V_T^+ - V_T^-$
l lysteresis voltage	VH	3.3		0.35	_	V	V - V
		5.0		0.45	_		
		Min to Max	V _{CC} -0.1	1	_		$I_{OH} = -50 \mu A$
		1.65	1.4		_		$I_{OH} = -1 \text{ mA}$
	V _{он}	2.3	2.0		_		$I_{OH} = -2 \text{ mA}$
		3.0	2.48		_		$I_{OH} = -6 \text{ mA}$
Output voltage		4.5	3.8		_	V	$I_{OH} = -12 \text{ mA}$
Output voltage		Min to Max	_		0.1	V	$I_{OL} = 50 \mu A$
		1.65	_		0.3		$I_{OL} = 1 \text{ mA}$
	V_{OL}	2.3	_		0.4		$I_{OL} = 2 \text{ mA}$
		3.0	_		0.44		$I_{OL} = 6 \text{ mA}$
		4.5			0.55		I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_		±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Off state output current	l _{OZ}	Min to Max	_	_	±5	μΑ	$V_0 = 5.5 \text{ V or GND}$
Quiescent supply current	I _{CC}	5.5	_	_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I _{OFF}	0	_	_	5	μА	V_{IN} or $V_O = 0$ to 5.5 V
Input capacitance	C _{IN}	3.3	_	3.0	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

• $V_{CC} = 1.8 \pm 0.15 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = -40	Ta = -40 to 85°C		Test	FROM	ТО
item	Syllibol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	13.5	23.5	1.0	26.0	ne	C _L = 15 pF	Α	Υ
delay time	t _{PHL}	_	19.0	33.0	1.0	36.0		$C_L = 50 pF$		
Enable time	t _{ZH}	_	13.7	26.5	1.0	29.0	no	$C_L = 15 pF$	ŌĒ	V
Enable time	t_{ZL}	_	20.5	36.0	1.0	38.0	ns	$C_L = 50 pF$	OE	Y
Disable time	t _{HZ}	_	8.3	20.0	1.0	22.5	no	$C_L = 15 pF$	ŌĒ	V
	t_{LZ}	_	13.0	29.5	1.0	32.0	ı ne	$C_L = 50 pF$	OE	l i

$\bullet \quad V_{CC} = 2.5 \pm 0.2 \ V$

Item	Symbol	Ta = 25°C			Ta = -40	Ta = -40 to 85°C		Test	FROM	ТО
item	Syllibol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	6.8	13.0	1.0	15.5	ns	$C_L = 15 pF$	Α	V
delay time	t _{PHL}	— 8.7 16.5 1.0 18.5	113	$C_L = 50 pF$	^	'				
Enable time	t _{ZH}	_	7.0	13.0	1.0	15.5	no	$C_L = 15 pF$	ŌĒ	Υ
Enable time	t _{ZL}	_	8.8	16.5	1.0	18.5	ns	$C_L = 50 pF$		
Disable time	t _{HZ}	_	5.1	14.7	1.0	17.0	- ns	C _L = 15 pF	ŌĒ	Υ
Disable time	t_{LZ}	_	7.3	18.2	1.0	20.5		$C_L = 50 pF$	5	

• $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Item	Cumhal	Ta = 25°C			Ta = -40 to 85°C		Unit	Test	FROM	ТО
	Symbol	Min	Тур	Max	Min	Max	Onit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	4.8	8.0	1.0	9.5	ne	$C_L = 15 pF$	А	Υ
delay time	t _{PHL}	_	6.1	11.5	1.0	13.0		$C_L = 50 pF$	Α	
Enable time	t _{ZH}	_	4.8	8.0	1.0	9.5	nc	$C_L = 15 pF$	ŌĒ	V
Lilable time	t_{ZL}	_	6.2	11.5	1.0	13.0	ns	$C_L = 50 pF$	OE	ĭ
Disable time	t _{HZ}	_	4.1	9.7	1.0	11.5	nc	$C_L = 15 pF$	ŌĒ	V
	t_{LZ}	_	5.5	13.2	1.0	15.0	ns	C _L = 50 pF	OE	ī

$\bullet \quad V_{CC} = 5.0 \pm 0.5 \ V$

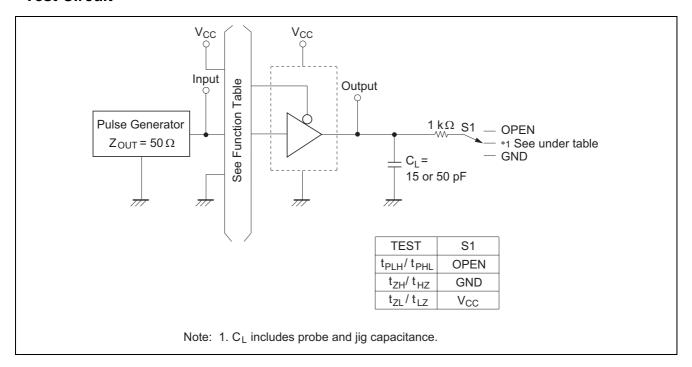
Item	Symbol	Ta = 25°C			Ta = -40	Ta = -40 to 85°C		Test	FROM	то
iteiii		Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	3.4	5.5	1.0	6.5	ne	$C_L = 15 pF$	Α	
delay time	time t _{PHL} —	_	4.3	7.5	1.0	8.5	115	$C_L = 50 pF$	^	'
Enable time	t _{zH}	_	3.4	5.1	1.0	6.0	20	$C_L = 15 pF$	ŌĒ	Y
Lilable time	t _{ZL}	_	4.4	7.1	1.0	8.0	ns	$C_L = 50 pF$		
Disable time	t _{HZ}	_	3.2	6.8	1.0	8.0	ne	$C_L = 15 pF$	ŌĒ	Υ
Disable time	t_{LZ}	_	4.0	8.8	1.0	10.0	ns	$C_L = 50 pF$	5	

Operating Characteristics

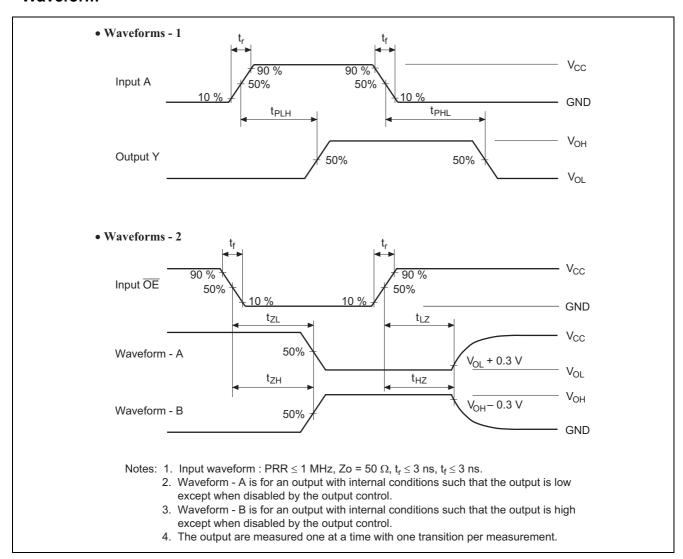
• $C_L = 50 pF$

Item	Symbol	V _{CC} (V)	Ta = 25°C			Unit	Test Conditions	
	Syllibol		Min	Тур	Max	Oilit	rest Conditions	
Power dissipation	C	3.3	_	10.5	_	pF	f = 10 MHz	
capacitance	C_{PD}	5.0		11.5	_	рг		

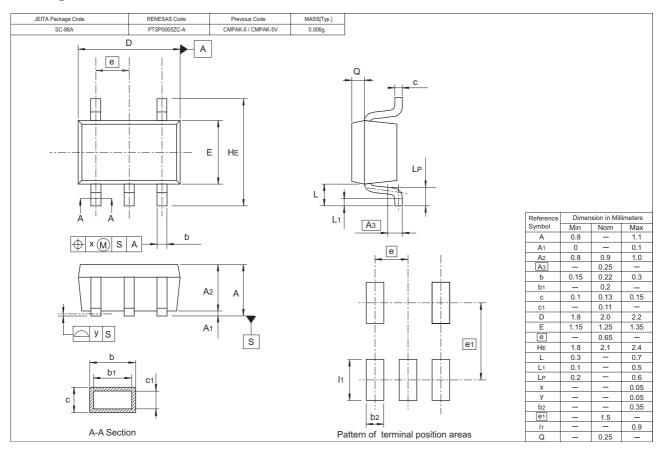
Test Circuit

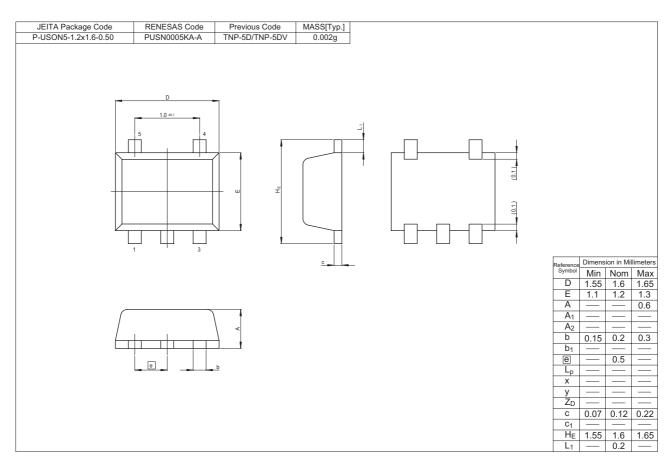


Waveform



Package Dimensions





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